



### 20V PNP POWER SWITCHING TRANSISTOR IN SOT323

### **Features**

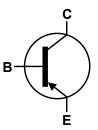
- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -1A Continuous Collector Current
- I<sub>CM</sub> = -3A Peak Pulse Current
- Low Saturation Voltage -250mV Max @ I<sub>C</sub> = -1A.
- $R_{CE(SAT)}$  = 200m $\Omega$  @ 1A for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- Excellent h<sub>FE</sub> Characteristics up to 3A
- Complementary NPN Type: ZUMT618
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

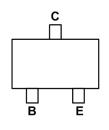
- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (approximate)







Device Symbol



Top View Pin-Out

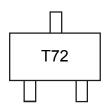
## Ordering Information (Notes 4)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
ZUMT718TA	AEC-Q101	T72	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



T72 = Product Type Marking Code

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## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-20	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Peak Pulse Current	I <sub>CM</sub>	-3	Α
Continuous Collector Current	Ic	-1	Α
Base Current	Ι <sub>Β</sub>	-200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D	385	mW	
Power Dissipation	(Note 6)	P <sub>D</sub>	500		
Thermal Decistores Lunction to Ambient	(Note 5)	Б	325	00/14/	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	250	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	350	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with collector lead on 10mm x 8mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the collector lead is on a 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



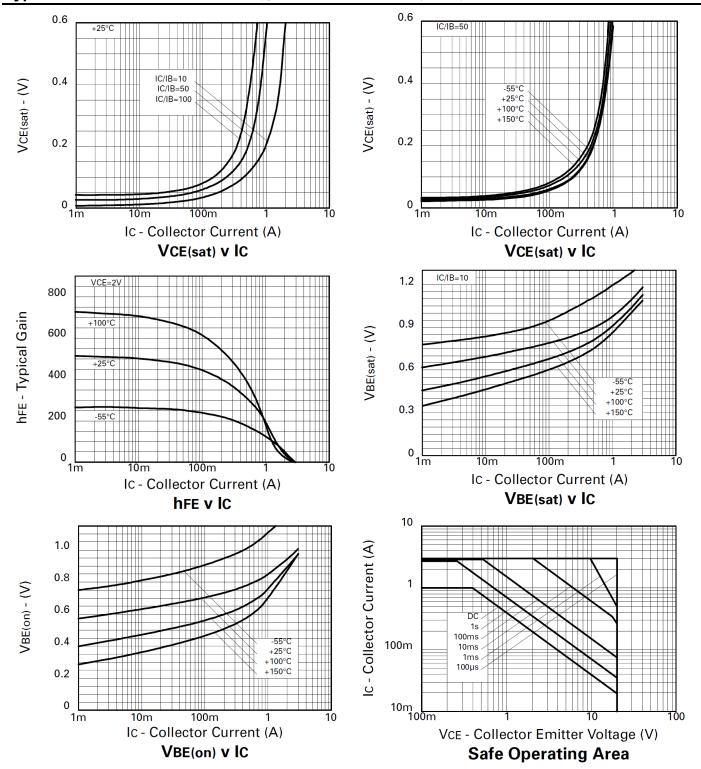
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	-20	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage	V <sub>CEO</sub>	-20	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	V <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	_	-10	nA	V <sub>CB</sub> = -15V
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	_	-10	nA	V <sub>EB</sub> = -4.0V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	_	-10	nA	V <sub>CES</sub> = -15V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h <sub>FE</sub>	300 300 200 100 20	490 450 315 160 75	_	_	$\begin{split} I_{C} &= -10\text{mA}, \ V_{CE} = -2.0\text{V} \\ I_{C} &= -0.1\text{A} \ , \ V_{CE} = -2.0\text{V} \\ I_{C} &= -0.5\text{A}, \ V_{CE} = -2.0\text{V} \\ I_{C} &= -1\text{A}, \ V_{CE} = -2.0\text{V} \\ I_{C} &= -1.5\text{A}, \ V_{CE} = -2.0\text{V} \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-33.5 -80 -130 -180	-45 -110 -175 -250	mV mV mV	$\begin{split} &I_{C} = -0.1A, \ I_{B} = -10 mA \\ &I_{C} = -0.25A, \ I_{B} = -10 mA \\ &I_{C} = -0.5A, \ I_{B} = -20 mA \\ &I_{C} = -1A, \ I_{B} = -100 mA \end{split}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-970	-1100	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage	V <sub>BE(ON)</sub>	_	-850	-1100	mV	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2.0V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>	_	11	_	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	_	60	_	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -1A,
Turn-Off Time	t <sub>(off)</sub>		135	_	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
Current Gain-Bandwidth Product	f <sub>T</sub>	_	210	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



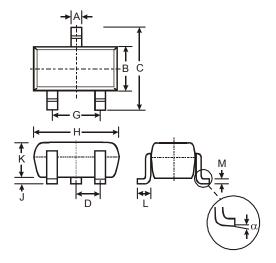
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

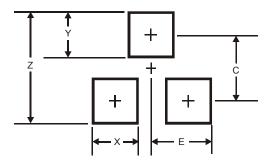
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323					
Dim	Min	Max	Тур		
Α	0.25	0.40	0.30		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	-	-	0.65		
G	1.20	1.40	1.30		
Н	1.80	2.20	2.15		
7	0.0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
М	0.10	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
F	1.0



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